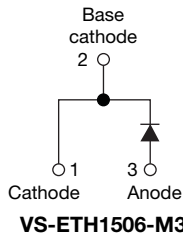


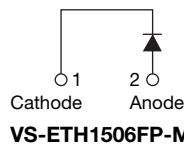
Hyperfast Rectifier, 15 A FRED Pt[®]



2L TO-220AC



2L TO-220 FULL-PAK



FEATURES

- Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package ($V_{INS} = 2500 V_{RMS}$)
- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47



RoHS
COMPLIANT
HALOGEN
FREE

DESCRIPTION/APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

PRODUCT SUMMARY

| Package | 2L TO-220AC, 2L TO-220FP |
|-----------------|--------------------------|
| $I_{F(AV)}$ | 15 A |
| V_R | 600 V |
| V_F at I_F | 2.45 V |
| t_{rr} (typ.) | 21 ns |
| T_J max. | 175 °C |
| Diode variation | Single die |

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|---|----------------|-----------------------|-------------|-------|
| Peak repetitive reverse voltage | V_{RRM} | | 600 | V |
| Average rectified forward current in DC | $I_{F(AV)}$ | $T_C = 149\text{ °C}$ | 15 | A |
| | | $T_C = 94\text{ °C}$ | | |
| Non-repetitive peak surge current | I_{FSM} | $T_J = 25\text{ °C}$ | 160 | |
| Operating junction and storage temperatures | T_J, T_{Stg} | | - 65 to 175 | °C |

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|-------------------------------------|---------------|--|------|------|------|---------|
| Breakdown voltage, blocking voltage | V_{BR}, V_R | $I_R = 100\ \mu A$ | 600 | - | - | V |
| | | | | | | |
| Forward voltage | V_F | $I_F = 15\text{ A}$ | - | 1.8 | 2.45 | |
| | | $I_F = 15\text{ A}, T_J = 150\text{ °C}$ | - | 1.25 | 1.6 | |
| Reverse leakage current | I_R | $V_R = V_R$ rated | - | 0.01 | 15 | μA |
| | | $T_J = 150\text{ °C}, V_R = V_R$ rated | - | 20 | 200 | |
| Junction capacitance | C_T | $V_R = 600\text{ V}$ | - | 12 | - | pF |
| Series inductance | L_S | Measured lead to lead 5 mm from package body | - | 8 | - | nH |

VS-ETH1506-M3, VS-ETH1506FP-M3



Vishay Semiconductors Hyperfast Rectifier, 15 A FRED Pt®

| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified) | | | | | | | |
|---|-----------|--|---|------|------|-------|----|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Reverse recovery time | t_{rr} | $I_F = 1\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$ | - | 21 | 26 | ns | |
| | | $I_F = 15\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$ | - | 25 | 36 | | |
| | | $T_J = 25\text{ }^\circ\text{C}$ | - | 29 | - | | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | - | 65 | - | | |
| Peak recovery current | I_{RRM} | $T_J = 25\text{ }^\circ\text{C}$ | - | 3.9 | - | A | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | - | 7.0 | - | | |
| Reverse recovery charge | Q_{rr} | $T_J = 25\text{ }^\circ\text{C}$ | - | 60 | - | nC | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | - | 240 | - | | |
| Reverse recovery time | t_{rr} | $T_J = 125\text{ }^\circ\text{C}$ | $I_F = 15\text{ A}$ $di_F/dt = 800\text{ A}/\mu\text{s}$ $V_R = 390\text{ V}$ | - | 42 | - | ns |
| Peak recovery current | I_{RRM} | | | - | 21 | - | A |
| Reverse recovery charge | Q_{rr} | | | - | 480 | - | nC |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|----------------|--|-----------|------|------------|---------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T_J, T_{Stg} | | - 65 | - | 175 | $^\circ\text{C}$ |
| Thermal resistance, junction to case FULL-PAK | R_{thJC} | | - | 1.2 | 1.4 | $^\circ\text{C}/\text{W}$ |
| | | | - | 3.7 | 4.3 | |
| Thermal resistance, junction to ambient | R_{thJA} | Typical socket mount | - | - | 70 | |
| Typical thermal resistance, case to heatsink | R_{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | |
| Weight | | | - | 2 | - | g |
| | | | - | 0.07 | - | oz. |
| Mounting torque | | | 6 (5) | - | 12 (10) | kgf · cm (lbf · in) |
| Marking device | | Case style 2L TO-220AC | ETH1506 | | | |
| | | Case style 2L TO-220 FULL-PAK | ETH1506FP | | | |



VS-ETH1506-M3, VS-ETH1506FP-M3

Hyperfast Rectifier, 15 A FRED Pt[®] Vishay Semiconductors

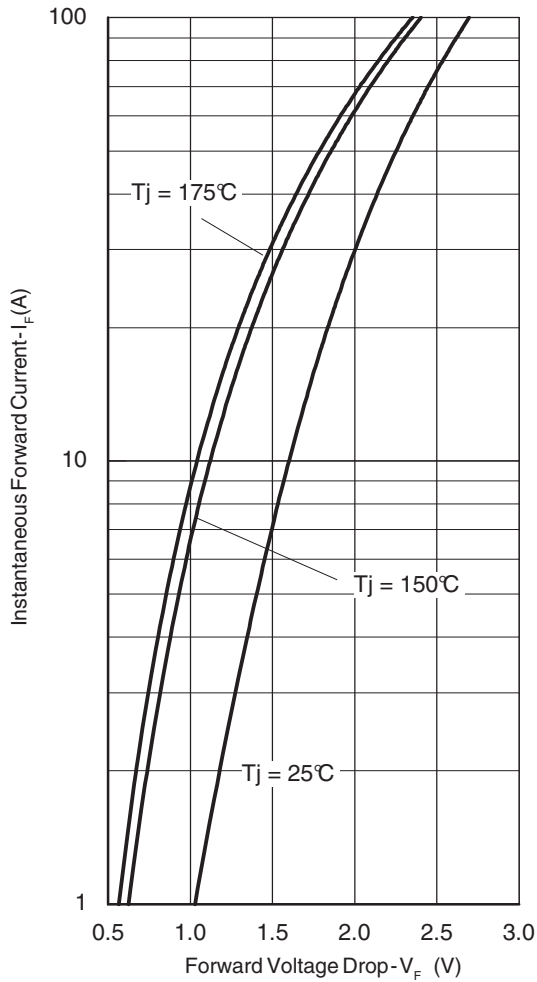


Fig. 1 - Typical Forward Voltage Drop Characteristics

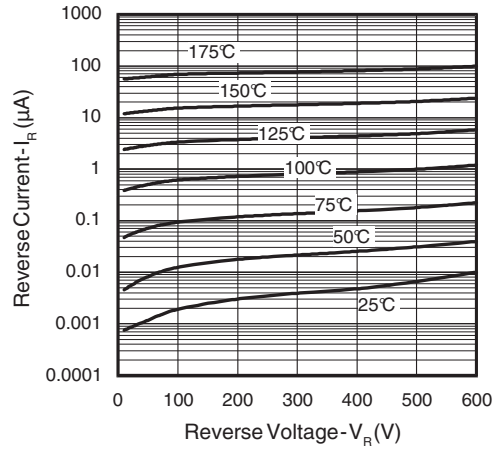


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

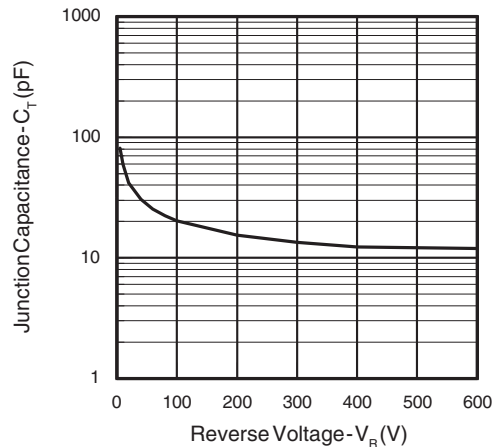


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

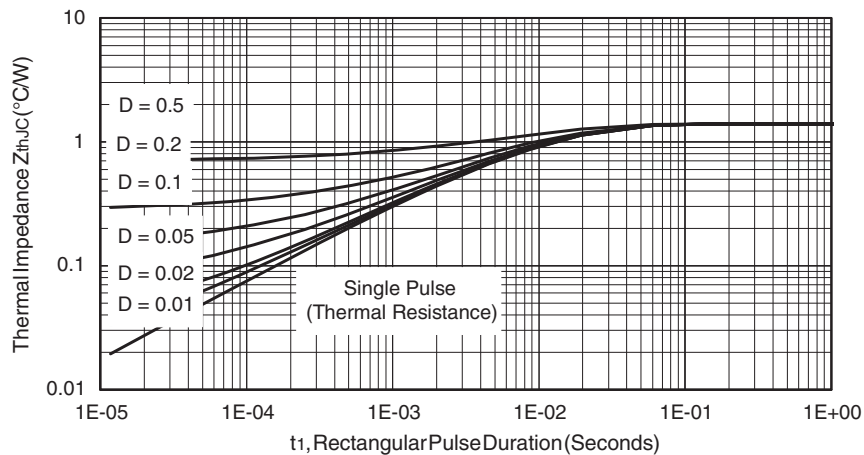


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

VS-ETH1506-M3, VS-ETH1506FP-M3

Vishay Semiconductors Hyperfast Rectifier, 15 A FRED Pt®

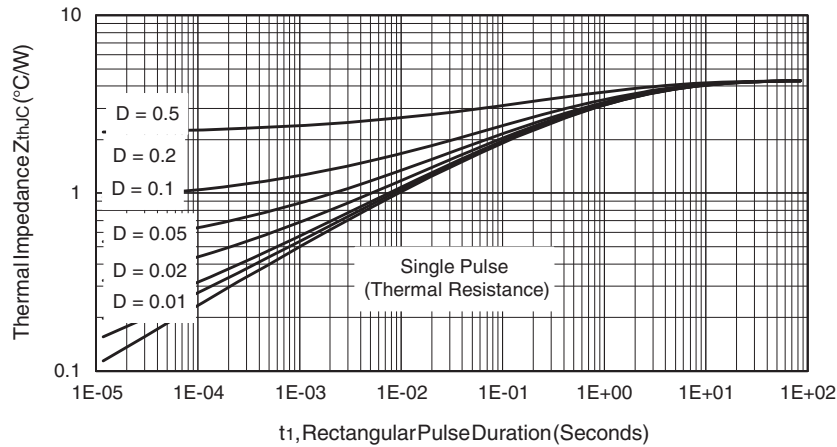


Fig. 5 - Maximum Thermal Impedance Z_{thJC} Characteristics (FULL-PAK)

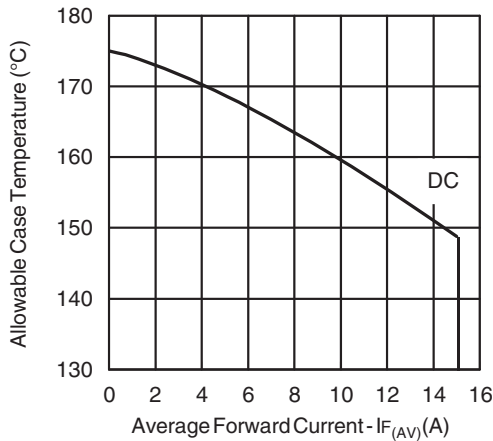


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

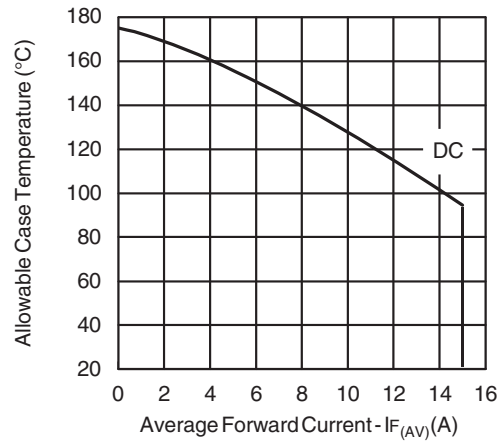


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

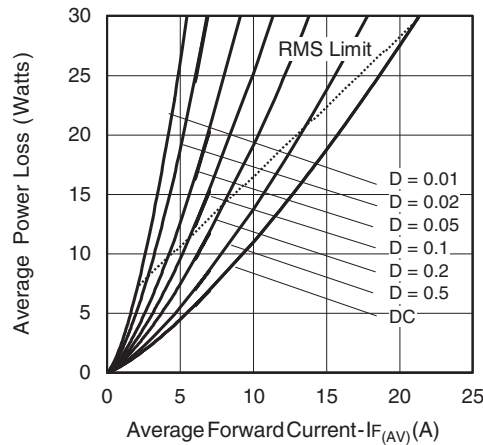


Fig. 8 - Forward Power Loss Characteristics

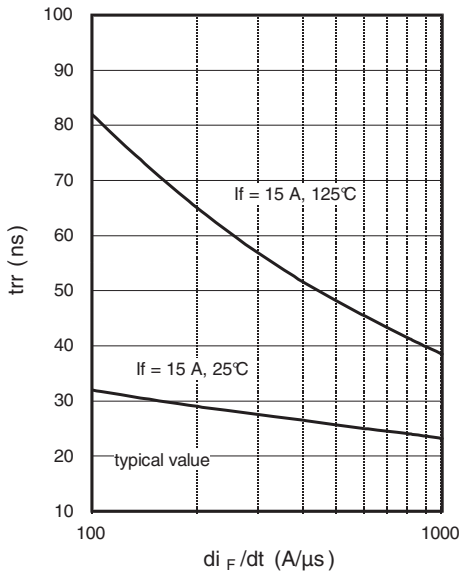


Fig. 9 - Typical Reverse Recovery vs. di_F/dt

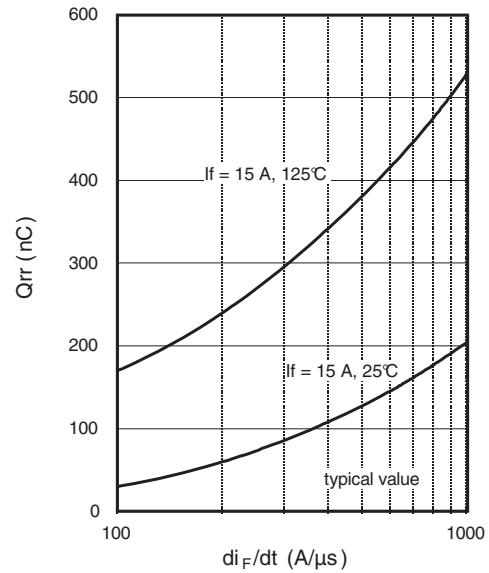
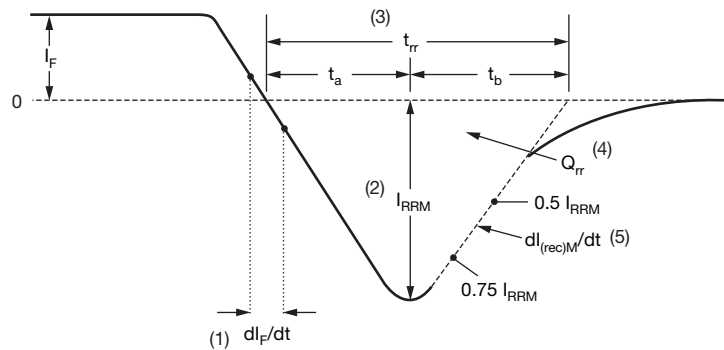


Fig. 10 - Typical Stored Charge vs. di_F/dt



Fig. 11 - Reverse Recovery Parameter Test Circuit



(1) di_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 12 - Reverse Recovery Waveform and Definitions

VS-ETH1506-M3, VS-ETH1506FP-M3

Vishay Semiconductors Hyperfast Rectifier, 15 A FRED Pt®



ORDERING INFORMATION TABLE

| | | | | | | | | |
|-------------|------------|----------|----------|----------|-----------|-----------|-----------|------------|
| Device code | VS- | E | T | H | 15 | 06 | FP | -M3 |
| | ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ | ⑧ |

- 1** - Vishay Semiconductors product
- 2** - Circuit configuration:
E = Single diode
- 3** - T = TO-220
- 4** - H = Hyperfast recovery time
- 5** - Current code: 15 = 15 A
- 6** - Voltage code: 06 = 600 V
- 7** -
 - None = TO-220
 - FP = FULL-PAK
- 8** - Environmental digit:
-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | |
|---------------------------------------|-------------------|------------------------|-------------------------|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION |
| VS-ETH1506-M3 | 50 | 1000 | Antistatic plastic tube |
| VS-ETH1506FP-M3 | 50 | 1000 | Antistatic plastic tube |

| LINKS TO RELATED DOCUMENTS | | |
|-----------------------------------|--------------------|--|
| Dimensions | 2L TO-220AC | www.vishay.com/doc?95259 |
| | 2L TO-220 FULL-PAK | www.vishay.com/doc?95260 |
| Part marking information | 2L TO-220AC | www.vishay.com/doc?95391 |
| | 2L TO-220 FULL-PAK | www.vishay.com/doc?95392 |

True 2 Pin TO-220

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | |
|-----------------|-------------|-------|-----------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| A | 4.32 | 4.57 | 0.170 | 0.180 |
| b | 0.71 | 0.91 | 0.028 | 0.036 |
| b_1 | 1.15 | 1.39 | 0.045 | 0.055 |
| c | 0.36 | 0.53 | 0.014 | 0.021 |
| D | 14.99 | 15.49 | 0.590 | 0.610 |
| E | 10.04 | 10.41 | 0.395 | 0.410 |
| e | 5.08 BSC | | 0.200 BSC | |
| F | 1.22 | 1.37 | 0.048 | 0.054 |
| H_1 | 5.97 | 6.47 | 0.235 | 0.255 |
| J_1 | 2.54 | 2.79 | 0.100 | 0.110 |
| L | 13.47 | 13.97 | 0.530 | 0.550 |
| $L_1^{(1)}$ | 3.31 | 3.81 | 0.130 | 0.150 |
| $\varnothing P$ | 3.79 | 3.88 | 0.149 | 0.153 |
| Q | 2.60 | 2.84 | 0.102 | 0.112 |

Notes

⁽¹⁾ Lead dimension and finish uncontrolled in L_1

- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controlling dimension: Inch



True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIMETERS | | INCHES | |
|----------------|--------------|-------|---------------|-------|
| | MIN. | MAX. | MIN. | MAX. |
| A | 4.53 | 4.93 | 0.178 | 0.194 |
| b | 0.71 | 0.91 | 0.028 | 0.036 |
| b ₁ | 1.15 | 1.39 | 0.045 | 0.055 |
| C | 0.36 | 0.53 | 0.014 | 0.021 |
| D | 15.67 | 16.07 | 0.617 | 0.633 |
| E | 9.96 | 10.36 | 0.392 | 0.408 |
| e | 5.08 typical | | 0.200 typical | |
| F | 2.34 | 2.74 | 0.092 | 0.107 |
| H ₁ | 6.50 | 6.90 | 0.256 | 0.272 |
| J ₁ | 2.56 | 2.96 | 0.101 | 0.117 |
| L | 12.78 | 13.18 | 0.503 | 0.519 |
| L ₁ | 2.23 | 2.63 | 0.088 | 0.104 |
| Ø Q | 2.98 | 3.38 | 0.117 | 0.133 |
| Q ₁ | 3.10 | 3.50 | 0.122 | 0.138 |
| Q ₂ | 14.80 | 15.20 | 0.583 | 0.598 |
| θ | 0° | 5° | 0° | 5° |



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.